2017-00082 - Procedural, Stochastic, and Fabricable Microstructures

Level of qualifications required: PhD or equivalent
Function: PhD Position
Level of experience: Recently graduated

Context
This PhD position is funded by ANR JCJC 2017 MuFFin.

Assignment

Contacts
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Team
Alice, INRIA Nancy Grand-Est.

Main activities

Context
Additive Manufacturing (AM) technologies are now capable of fabricating microstructures at the scale of microns, therefore enabling to precise control of the macroscopic physical behavior. This control empowers a wide range of industrial applications by bringing high-performance customized materials. In particular, a promising venue lies in the optimization of material properties such as rigidity or impact absorption.

Microstructures for AM will play a decisive role in the factory of the future, but several challenges remain aside [1]. The dimension of the objects being printed increases, and concurrently, the available printing resolution becomes finer. Thus, the geometry size of microstructures is drastically escalating. From a computational viewpoint, explicitly storing the microstructure geometry (e.g. in an STL file), will eventually render infeasible the whole computational pipeline (numerical simulation, visualization, and computational design of microstructures). From a material science viewpoint, it remains a challenge to properly embed and grade microstructures within an object, and to ensure that they can be directly fabricated with AM processes.

State of the art methods consider periodic microstructures [4, 5, 6], offering compact storage, efficient display, and simulation of the macroscopic physical behavior. However, due to their constrained global structure, periodic microstructures exhibit a poor grading behavior, specially when targeting anisotropic material properties that follow an arbitrary orientation field.

Project description
The objective of the thesis is to tackle the aforementioned interdisciplinary challenges by considering procedural, stochastic, and fabricable microstructures, with a controlled macroscopic physical behavior. We have recently contributed novel techniques in this area of research [2, 3].

How to apply
Send the following documents to jonas.martinez-bayona@inria.fr in a single ZIP file:

- CV.
- A motivation letter describing your interest in this topic.
- Your degree certificates and transcripts for Bachelor and Master (or the last 5 years if not applicable).
- Master thesis (or equivalent) if it is already completed, or a description of the work in progress, otherwise.
- Publications, if any (it is not expected that you have any).

In addition, at least one recommendation letter from the person who supervises(d) your Master thesis (or research project or internship) should be sent. At most two other recommendation letters may be sent. The recommendation letter(s) should be sent directly by their author to jonas.martinez-bayona@inria.fr

Applications to be sent as soon as possible.

Conditions for
The detailed description of the PhD proposal can be found at http://mfx.loria.fr/muffin-phd/

Skills

Language

English.

Benefits package

- Subsidised catering service
- Partially-reimbursed public transport
- Social security
- Paid leave
- Flexible working hours
- Sports facilities

Remuneration

Rémunération : 1982,00€ brut mensuel

application

Defence Security :
This position is likely to be situated in a restricted area (ZRR), as defined in Decree No. 2011-1425 relating to the protection of national scientific and technical potential (PPST). Authorisation to enter an area is granted by the director of the unit, following a favourable Ministerial decision, as defined in the decree of 3 July 2012 relating to the PPST. An unfavourable Ministerial decision in respect of a position situated in a ZRR would result in the cancellation of the appointment.

Recruitment Policy :
As part of its diversity policy, all Inria positions are accessible to people with disabilities.

Warning: you must enter your e-mail address in order to save your application to Inria. Applications must be submitted online on the Inria website. Processing of applications sent from other channels is not guaranteed.